



MMBTA55 / MMBTA56

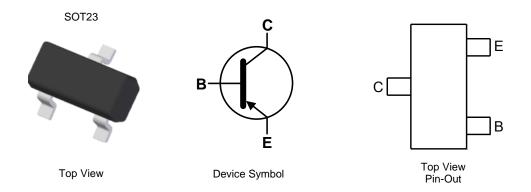
PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Complementary NPN Type: MMBTA05 / MMBTA06
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBTA55-7-F	AEC-Q101	K2G	7	8	3,000
MMBTA56-7-F	AEC-Q101	K2G	7	8	3,000
MMBTA56Q-7-F	Automotive	K2G	7	8	3,000
MMBTA56Q-13-F	Automotive	K2G	13	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

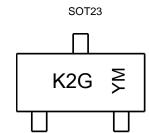
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

 Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} \mathsf{K2G} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex: C} = 2015) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex: 9} = \mathsf{September}) \end{array}$

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	С	D	E	F	G	Н		J	К	L	М	Ν
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	g	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	MMBTA55	MMBTA56	Unit
Collector-Base Voltage	V _{CBO}	-60	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	-80	V
Emitter-Base Voltage	V _{EBO}	-4	.0	V
Collector Current - Continuous	Ι _C	-5	00	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Dower Dissinction	(Note 6)	P	310	mW
Power Dissipation	(Note 7)	P _D	350	TTIVV
Thermal Resistance, Junction to Ambient	(Note 6)	R	403	°C/W
	(Note 7)	R _{0JA}	357	C/W
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	350	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air

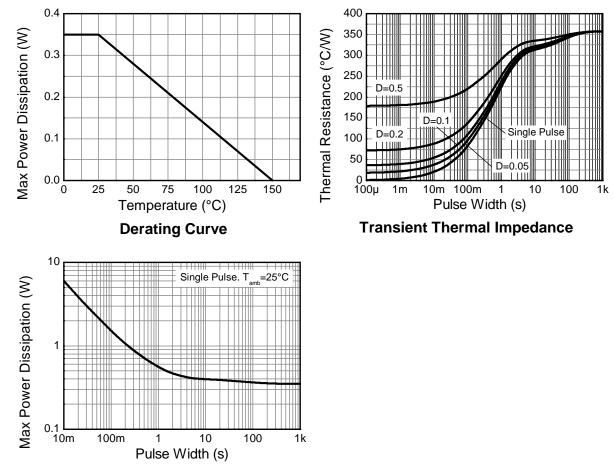
conditions whilst operating in a steady-state.

7. Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation



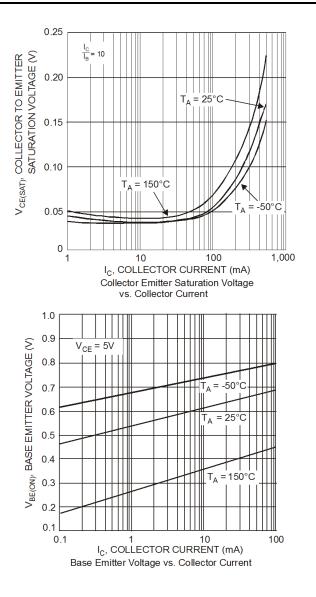
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

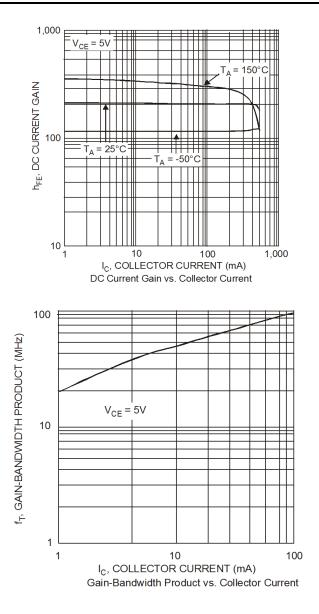
Characteristic			Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 10)				•		÷
Collector-Base Breakdown Voltage	MMBTA55 MMBTA56	BV _{CBO}	-60 -80	—	V	$I_{\rm C} = -100 \mu {\rm A}, \ I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	MMBTA55 MMBTA56	BV _{CEO}	-60 -80	—	V	$I_{\rm C} = -1.0 {\rm mA}, \ I_{\rm B} = 0$
Emitter-Base Breakdown Voltage		BV _{EBO}	-5.0	-4.0	_	$I_{\rm E} = -100 \mu A$, $I_{\rm C} = 0$
Collector Cut-Off Current	MMBTA55 MMBTA56	I _{CBO}	_	-100	nA	$V_{CB} = -60V, I_E = 0$ $V_{CB} = -80V, I_E = 0$
Collector Cut-Off Current		ICEX	—	-100	nA	$V_{CE} = -60V, I_{BO} = 0V$ $V_{CE} = -80V, I_{BO} = 0V$
ON CHARACTERISTICS (Note 10)						-
DC Current Gain		h _{FE}	100	_	—	$I_{C} = -10mA, V_{CE} = -1.0V$ $I_{C} = -100mA, V_{CE} = -1.0V$
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	_	-0.25	V	$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -10 {\rm mA}$
Base-Emitter Saturation Voltage	VBE(SAT)		-1.2	V	I _C = -100mA, V _{CE} = -1.0V	
SMALL SIGNAL CHARACTERISTICS				•	•	÷
Current Gain-Bandwidth Product		f⊤	50	_	MHz	$V_{CE} = -1.0V, I_C = -100mA, f = 100MHz$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

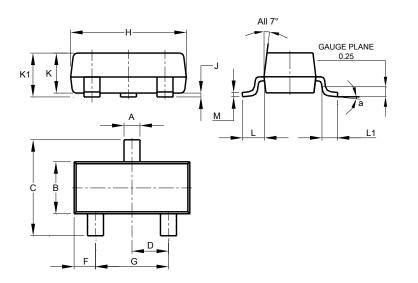






Package Outline Dimensions

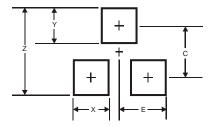
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
в	1.20	1.40	1.30				
c	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
H	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а		8°					
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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